



IAP-SEMINAR

EINLADUNG

Termin: **Dienstag, 21.1.2014 um 16:00 Uhr**
Ort: **Technische Universität Wien,
Institut für Angewandte Physik,
Seminarraum 134A, Turm B (gelbe Leitfarbe), 5. OG
1040 Wien, Wiedner Hauptstraße 8-10**

Vortragender: **Prof. Taro Hitosugi**
Advanced Institute for Materials Research (AIMR),
Tohoku University/Japan

Thema: **Scanning tunneling microscopy/spectroscopy of
LaAlO₃/SrTiO₃ heterostructures**

Kurzfassung

We report on the initial growth nature of sub-unit cell (UC) SrTiO₃ (STO) and LaAlO₃ (LAO) films formed on top of STO(001)-(root13×root13)-R33.7° substrate surfaces, using a scanning tunneling microscopy/spectroscopy (STM/STS) combined with pulsed laser deposition (PLD). The STM/STS imaging of sub-UC LAO islands reveals that a TiO_x layer of the SrTiO₃ substrate has transferred to the topmost surface of the LaAlO₃ layer, indicating that the TiO_x layer can be viewed as a graphene-like one unit-cell TiO_x sheet. This structure can be regarded as a new oxide nano material. Further, we found that the surface structures affects electron transport properties at LAO/STO interfaces. These findings on the atomic-scale nature of perovskite growth lead to preparation of higher-quality thin films and surfaces/interfaces exhibiting novel electronic and magnetic properties.

*Alle interessierten Kolleginnen und Kollegen sind zu diesem Seminar
(45 min mit anschließender gemeinsamer Diskussion) herzlich eingeladen.*

*U. Diebold e.h.
(Seminar-Chairperson)*

*H. Störi e.h.
(LVA-Leiter)*